

20A Low Barrier Diode

■ Features

- · Low forward voltage drop.
- Excellent high temperature stability.
- Fast switching capability.
- Suffix "G" indicates Halogen-free part, ex.CS20L100CTG-A.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

■ Mechanical data

• Epoxy: UL94-V0 rated flame retardant.

 $\bullet \ {\tt Case: JEDEC\ TO-220AB\ molded\ plastic\ body}.$

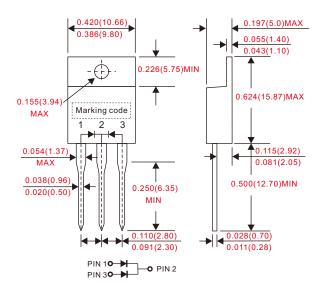
• Terminals : Solder plated, solderable per MIL-STD-750, Method 2026.

Polarity: As marked.Mounting Position : Any.

• Weight: Approximated 2.25 gram.

Outline

TO-220AB



Dimensions in inches and (millimeters)

■ Maximum ratings and electrical characteristics

Rating at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Conditions	Symbol	CS20L100CT-A	UNIT
Marking code			CS20L100CT	
Peak repetitive reverse voltage		V _{RRM}		
Working peak reverse voltage		V _{RWM}	100	V
DC blocking voltage		V _{RM}		
Forward rectified current (total device)		I _o	20	Α
Forward surge current (per diode)	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}	250	А
Peak repetitive reverse surge current (per diode)	2us - 1kHz	I _{RRM}	3	А
Thermal resistance(1) (per diode)	Junction to case	R _{eJC}	2	°C/W
Operating and Storage temperature		T _J , T _{STG}	-65 ~ +175	°C

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward voltage drop (per diode)	I _F = 10A, T _J = 25°C	V _F			750	mV
	I _F = 10A, T _J = 125°C				640	
	$I_F = 20A, T_J = 25^{\circ}C$				850	
Reverse current (per diode)	$V_R = V_{RRM} T_J = 25^{\circ}C$	l _R			0.1	mA
	$V_R = V_{RRM} T_J = 125^{\circ}C$				10	

Note: 1.Thermal resistance from junction to case per leg, with heatsink size(1.35" x 0.95" x 0.18") Al-plate.

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■ Rating and characteristic curves

Fig. 1 - Forward Power Dissipation (per diode)

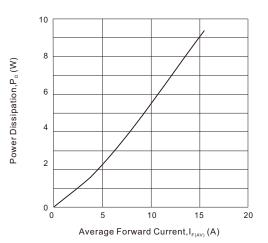


Fig. 2 - Instantaneous Forward Characteristics (per diode)

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T_A=150°C

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T_A=100°C

T_A=25°C

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Fig. 3 - Reverse Characteristics (per diode)

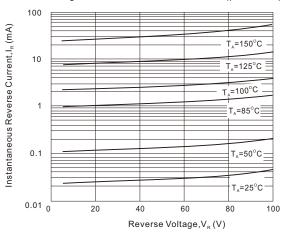
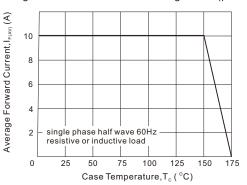


Fig.4 - Forward Current Derating Curve (per diode)



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